MCH6437

N-Channel Power MOSFET 20V, **7A**, **24m**Ω, Single MCPH6

Features

- ON-resistance RDS(on)1=18m Ω (typ.)
- 1.8V drive
- · Protection diode in

Specifications

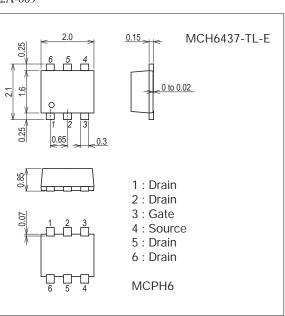
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	ID		7	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	28	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (1200mm ² ×0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7022A-009



Product & Package Information • Package

: MCPH6

: SC-88, SC-70-6, SOT-363

Marking

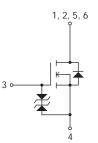
• JEITA, JEDEC • Minimum Packing Quantity : 3,000 pcs./reel

Taping Type : TL

0



Electrical Connection



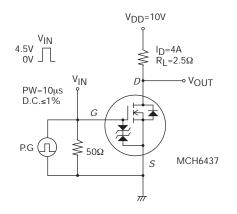
ON Semiconductor®

http://onsemi.com

Electrical Characteristics at Ta=25°C

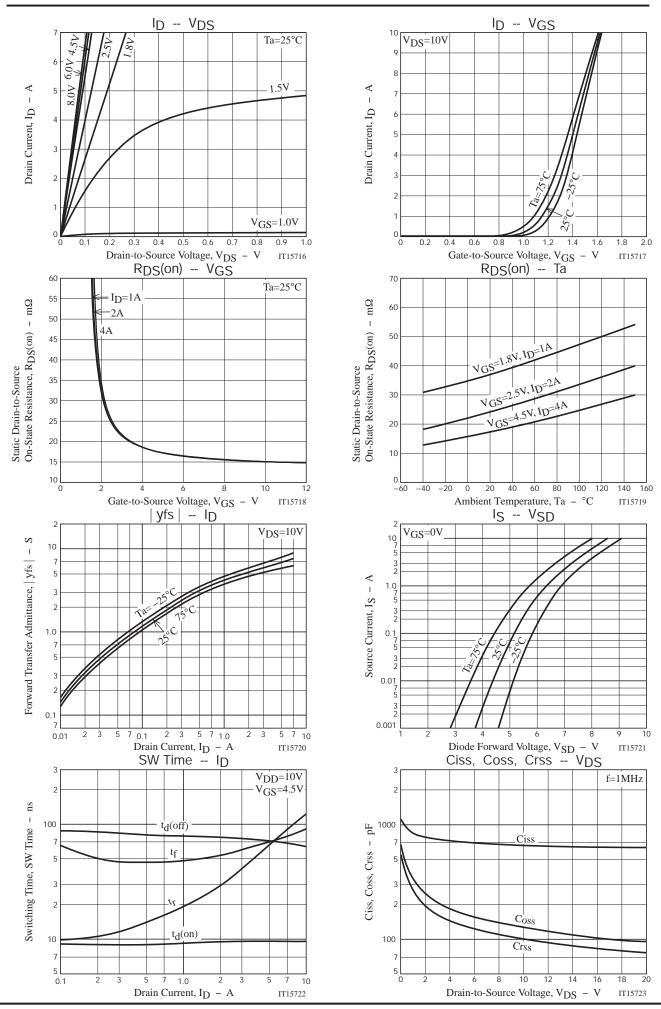
Parameter	Symbol	Conditions	Ratings			Linit
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =4A		6.2		S
	R _{DS} (on)1	ID=4A, VGS=4.5V		18	24	mΩ
Static Drain-to-Source On-State Resistance	R _{DS} (on)2	ID=2A, VGS=2.5V		25	35	mΩ
	R _{DS} (on)3	ID=1A, VGS=1.8V		38	65	mΩ
Input Capacitance	Ciss			660		рF
Output Capacitance	Coss	VDS=10V, f=1MHz		125		рF
Reverse Transfer Capacitance	Crss]		100		рF
Turn-ON Delay Time	t _d (on)			9.7		ns
Rise Time	tr			53		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		72		ns
Fall Time	tf]		65		ns
Total Gate Charge	Qg			8.4		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4.5V, I _D =7A		1.0		nC
Gate-to-Drain "Miller" Charge	Qgd	1		2.4		nC
Diode Forward Voltage	V _{SD}	IS=7A, VGS=0V		0.81	1.2	V

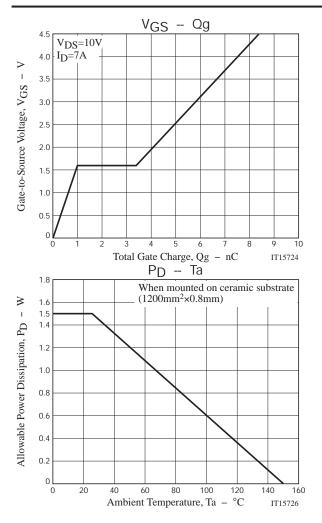
Switching Time Test Circuit

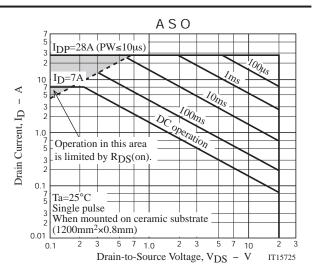


Ordering Information

Device	Package	Shipping	memo
MCH6437-TL-E	MCPH6	3,000pcs./reel	Pb Free







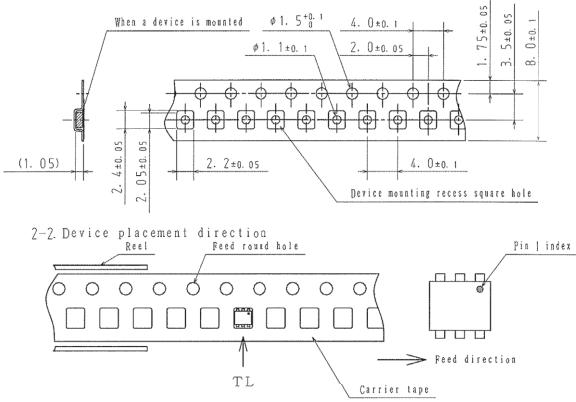
Taping Specification MCH6437-TL-E

1. Packing Format

Package Name	Carrier Tape	Maximun Number of devices contained (pcs)		Packing format	
	Туре	Reel [aner b	ox Outer box	Inner BOX (C-1) Outer BOX (A-7)	
MCPH6	MCP4	3, 000 15, 0	0 90,000	5 reels contained 6 inner boxes contained	
				Dimensions:mm (external) Dimensions:mm (external)	
				183×72×185 440×195×210	
<u>Reel label, Inner box label</u> (unit:mm) <u>(unit:mm)</u> <u>Packing method</u> <u>Reel label, Inner box label</u> It is a label at the time of factory shipment The form of a label may change in physical distribution process.					
	Type LOT Quan Orig	No> tity -> in ->	(9) TYPE 0000 111111111111111111111111111111111	6 9 0 0 0 0 0 0 HIMHING HIMHING 11 DEAD PREE X HIMHING HIMHING 10 C * (DIFFUSION: *****) 10 C * 10 C *	
	<u>Reella</u>		The LEAD F	EE 3 JEITA Phase 3A	

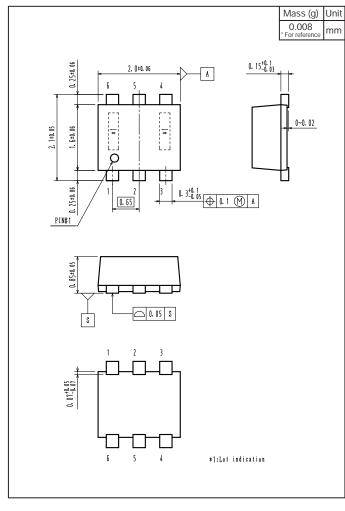
2. Taping configuration

2-1. Carrier tape size (unit:mm)

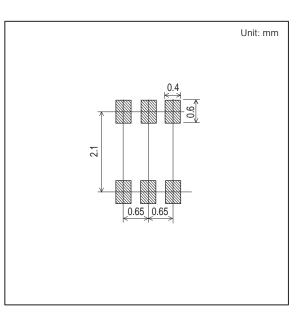


Those with pin 1 index on the feed hole side TL

Outline Drawing MCH6437-TL-E



Land Pattern Example



Note on usage : Since the MCH6437 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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